

# **GLF71305**

# Nano-Current Consumed, I<sub>Q</sub>Smart<sup>™</sup> LoadSwitch with Slew Rate Control

**Product Specification** 

#### **DESCRIPTION**

The GLF71305 is an ultra-efficiency, 2.0 A rated, Load Switch with integrated slew rate control. The best in class efficiency makes it an ideal choice for use in IoT, mobile, and wearable electronics.

The GLF71305 features an ultra-efficient  $I_QSmart^{TM}$  technology that supports the lowest quiescent current ( $I_Q$ ) and shutdown current ( $I_{SD}$ ) in the industry. Low  $I_Q$  and  $I_{SD}$  solutions help designers to reduce parasitic leakage current, improve system efficiency, and increase battery lifetime.

The GLF71305 integrated slew rate control can also enhance system reliability by mitigating bus voltage swings during switching events. Where uncontrolled switches can generate high inrush currents that result in voltage droop and/or bus reset events, the GLF slew rate control specifically limits inrush current during turn-on to minimize voltage droop.

The GLF71305 Load Switch device supports an industry leading wide input voltage range and helps to improve operating life and system robustness. Furthermore, one device can be used in multiple voltage rail applications which helps to simplify inventory management and reduces operating cost.

The GLF71305 Load Switch device is small utilizing a wafer level chip scale package with 4 bumps in a 0.77 mm x 0.77 mm x 0.46 mm die size and a 0.4 mm bump pitch.

#### **FEATURES**

Wide Input Range: 1.5 V to 5.5 V
 6 Vabs max

Ultra-Low I<sub>Q</sub>: 3 nA @ 5.5 V<sub>IN</sub>

Ultra-Low I<sub>SD</sub>: 22 nA Typ @ 5.5 V<sub>IN</sub>

• Low  $R_{ON} = 34 \text{ m}\Omega \text{ Typ.} @ 5.5 \text{ V}_{IN}$ 

Iout Max = 2.0 A

Controlled Rise Time: 340 us at 3.3 V<sub>IN</sub>

• Integrated Output Discharge Switch

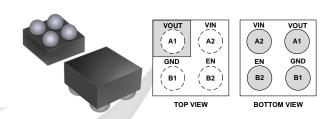
Wide Operating Temperature Range:

-40 °C ~ 85 °C HBM: 6 kV, CDM: 2 kV

#### **APPLICATIONS**

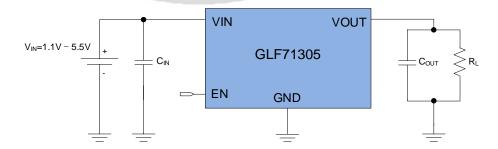
- Wearables
- Data Storage, SSD
- Mobile Devices
- Low Power Subsystems

### **PACKAGE**



0.77 mm x 0.77 mm x 0.46 mm WLCSP

#### APPLICATION DIAGRAM





# Nano-Current Consumed, I<sub>Q</sub>Smart<sup>™</sup> LoadSwitch with Slew Rate Control

### **ALTERNATE DEVICE OPTIONS**

Part Number	Top Mark	R <sub>ON</sub> (Typ) at 5.5 V	Output Discharge	EN Activity
GLF71305	Н	34 mΩ	85 Ω	High

## **FUNCTIONAL BLOCK DIAGRAM**

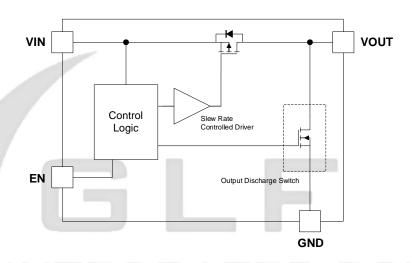


Figure 1. Functional Block Diagram

# **PIN CONFIGURATION**

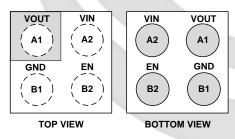


Figure 2. 0.77 mm x 0.77 mm x 0.46 mm WLCSP

### **PIN DEFINITION**

Pin#	Name	Description
A1	Vouт	Switch Output
A2	Vin	Switch Input. Supply Voltage for IC
B1	GND	Ground
B2	EN	Enable to control the switch.  Do not leave the EN pin floating

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### **ABSOLUTE MAXIMUM RATINGS**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions; extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Pa	Min.	Max.	Unit	
VIN, VOUT, VEN	Each Pin Voltage Range to GND	-0.3	6	V	
Іоит	Maximum Continuous Switch Current			2	Α
PD	Power Dissipation at T <sub>A</sub> = 25 °C		1	W	
T <sub>STG</sub>	Storage Junction Temperature	-65	150	°C	
T <sub>A</sub>	Operating Temperature Range	-40	85	°C	
θЈА	Thermal Resistance, Junction to Ambi		110	°C/W	
ESD	Electronic Dischause Completit	Human Body Model, JESD22-A114	6		1417
	Electrostatic Discharge Capability  Charged Device Model, JESD22-C101				kV

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Max.	Unit
VIN	Supply Voltage	1.5	5.5	V
T <sub>A</sub>	Ambient Operating Temperature	-40	+85	°C





# Nano-Current Consumed, I<sub>Q</sub>Smart<sup>™</sup> LoadSwitch with Slew Rate Control

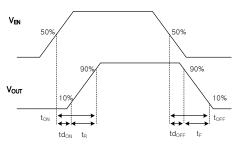
# **ELECTRICAL CHARACTERISTICS**

Values are at  $V_{IN} = 3.3 \text{ V}$  and  $T_A = 25 \,^{\circ}\text{C}$  unless otherwise noted.

Symbol	Parameter	Conditions			Тур.	Max.	Unit	
Basic Ope	eration			•	•			
VIN	Supply Voltage			1.5		5.5	V	
l-	Ouisseent Current	V <sub>IN</sub> = V <sub>EN</sub> =5.5 V, I <sub>OUT</sub> =0 mA			3			
lα	Quiescent Current	VIN = VEN =5.5 V, IOUT=0 mA,	Ta=85 °C <sup>(6)</sup>		7			
		EN = Disable, I <sub>OUT</sub> =0 mA, V <sub>IN</sub> =1.5 V			3			
		EN = Disable, I <sub>OUT</sub> =0 mA, V <sub>II</sub>	N=1.8 V		4			
		EN = Disable, I <sub>OUT</sub> =0 mA, V <sub>II</sub>	N=3.3 V		6		nA	
I <sub>SD</sub>	Shutdown Current	EN = Disable, Iout=0 mA, VII	N=4.5 V		9			
		EN = Disable, I <sub>OUT</sub> =0 mA, V <sub>II</sub>	<sub>N</sub> =5.5 V		22	50		
		EN = Disable, Iout=0 mA, VII	N=5.5 V, Ta=55 °C (2)		110			
		EN = Disable, I <sub>OUT</sub> =0 mA, V <sub>II</sub>	<sub>N</sub> =5.5V, Ta=85 °C <sup>(2)</sup>		600			
	On-Resistance		.,,	Ta=25 °C		34	47	
		V <sub>IN</sub> =5.5 V, I <sub>OUT</sub> = 500 mA	Ta=85 °C (2)		40		1	
_		V <sub>IN</sub> =3.3 V, I <sub>OUT</sub> = 500 mA	Ta=25 °C		42	56		
Ron			Ta=85 °C (2)		50		mΩ	
		V <sub>IN</sub> =1.8 V, I <sub>OUT</sub> = 300 mA	Ta=25 °C		68			
		V <sub>IN</sub> =1.5 V, I <sub>OUT</sub> = 100 mA	Ta=25 °C		75			
Rosc	Output Discharge Resistance	E <sub>N</sub> =Low, I <sub>FORCE</sub> = 10 mA	ED P		85	R	Ω	
V <sub>IH</sub>	EN Input Logic High Voltage	V <sub>IN</sub> =1.5 V - 1.8 V		0.5			V	
VIH	EN Input Logic Flight Voltage	V <sub>IN</sub> =1.8 V - 5.5 V		0.6			V	
VIL	EN Input Logic Low Voltage	V <sub>IN</sub> =1.5 V - 5.5 V				0.25	V	
V IL	Liv input Logic Low Voltage	V <sub>IN</sub> =1.8 V - 5.5 V				0.35	V	
Switching	Characteristics (1)			/				
t <sub>dON</sub>	Turn-On Delay	D. 450 O. C 0.4 uF		/	245			
t <sub>R</sub>	V <sub>OUT</sub> Rise Time	R <sub>L</sub> =150 Ω, C <sub>OUT</sub> =0.1 μF			340			
t <sub>dON</sub>	Turn-On Delay (2)	R <sub>L</sub> =500 Ω, C <sub>OUT</sub> =0.1 μF			230		- μs	
t <sub>R</sub>	Vout Rise Time (2)				330			
t <sub>dOFF</sub>	Turn-Off Delay (2)	R <sub>L</sub> =150 Ω, C <sub>ΟUT</sub> =0.1 μF			0.89			
tғ	V <sub>OUT</sub> Fall Time (2)				10			
tdOFF	Turn-Off Delay (2)	R <sub>L</sub> =500 Ω, C <sub>OUT</sub> =0.1 μF			1			
t <sub>F</sub>	Vout Fall Time (2)	KL=300 Ω, COUT=0.1 μΓ			13			

Notes:

- ton = t<sub>dON</sub> + t<sub>R</sub> , t<sub>OFF</sub> = t<sub>dOFF</sub> + t<sub>F</sub>
   By design; characterized, not production tested.
   Timing Diagram



# Nano-Current Consumed, IoSmart<sup>™</sup> LoadSwitch with Slew Rate Control

## TYPICAL PERFORMANCE CHARACTERISTICS

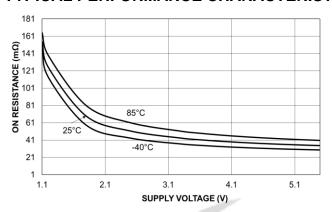


Figure 3. On-Resistance vs. Supply Voltage

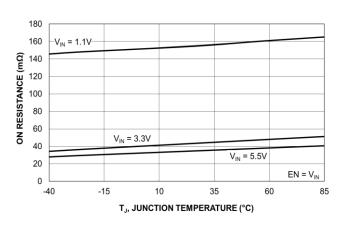


Figure 4. On-Resistance vs. Temperature

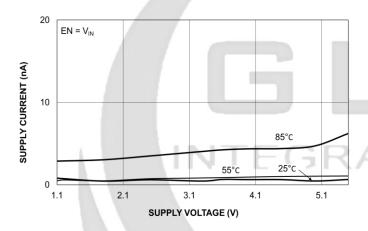


Figure 5. Quiescent Current vs. Supply Voltage

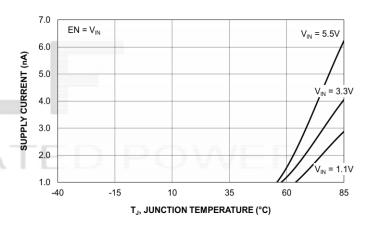


Figure 6. Quiescent Current vs. Temperature

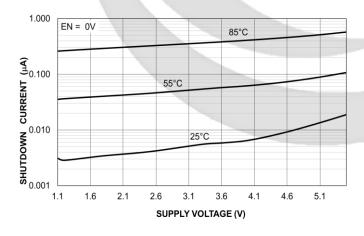


Figure 7. Shutdown Current vs. Supply Voltage

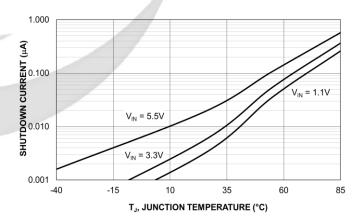


Figure 8. Shutdown Current vs. Temperature





# Nano-Current Consumed, IoSmart<sup>™</sup> LoadSwitch with Slew Rate Control

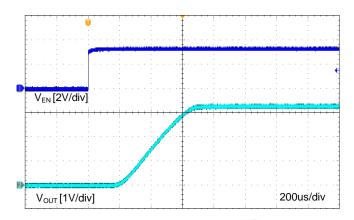


Figure 11. Turn-On Response  $\label{eq:Vin=3.3} V,\, C_{\text{IN}=1.0}\,\, uF,\, C_{\text{OUT}=0.1}\,\, uF,\, R_{\text{L}=150}\,\, \Omega$ 

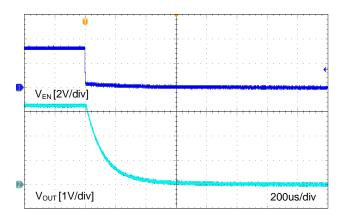


Figure 12. Turn-On Response  $\label{eq:Vin=3.3} V,\,C_{\text{IN}=1.0}\,\,uF,\,C_{\text{OUT}=0.1}\,\,uF,\,R_{\text{L}=500}\,\,\Omega$ 

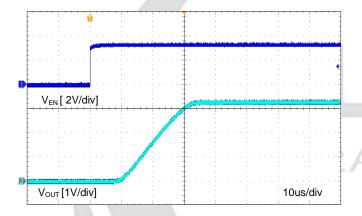


Figure 13. Turn-Off Response, Output Discharge  $V_{\text{IN}=3.3} \text{ V, C}_{\text{IN}=1.0} \text{ uF, C}_{\text{OUT}=0.1} \text{ uF, R}_{\text{L}=150} \ \Omega$ 

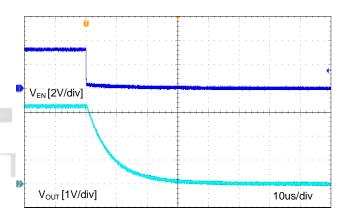


Figure 14. Turn-Off Response, Output Discharge V<sub>IN=3.3</sub> V, C<sub>IN=1.0</sub> uF, C<sub>OUT=0.1</sub> uF, R<sub>L=500</sub>  $\Omega$ 

# **GLF71305**



# Nano-Current Consumed, IoSmart™ LoadSwitch with Slew Rate Control

#### APPLICATION INFORMATION

The GLF71305 is a 2.0 A, Ultra-Efficient I<sub>Q</sub>Smart<sup>™</sup> LoadSwitch devices with a fixed slew rate control to limit the inrush current during turn on. Each device is capable of operating over a wide input range from 1.5 V to 5.5 V with very low on-resistance to reduce conduction loss. In the off state, these devices consume very low leakage current to avoid unwanted standby current and save limited input power.

#### **Input Capacitor**

A capacitor is recommended to be placed close to the V<sub>IN</sub> pin to reduce the voltage drop on the input power rail caused by transient inrush current at start-up. A higher input capacitor value can be used to further attenuate the input voltage drop.

### **Output Capacitor**

An output capacitor is recommended to mitigate voltage undershoot on the output pin the moment when the switch is turned off. Undershoot can be caused by parasitic inductance from board traces or intentional load inductances. If load inductances do exist, use of an output capacitor can improve output voltage stability and system reliability. The Cout capacitor should be placed close to the VOUT and GND pins.

#### EN pin

The GLF71305 can be activated by EN pin high level. Note that the EN pin is not allowed to be floating.

## **Output Discharge Function**

The GLF71305 has an internal discharge N-channel FET switch on the VOUT pin. When EN signal turns the main power FET to an off state, the N-channel switch turns on to discharge an output capacitor quickly.

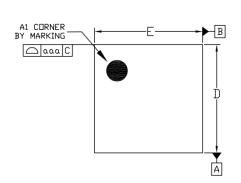
### **Board Layout**

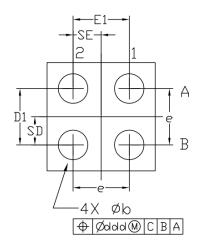
All traces should be as short as possible to minimize parasitic inductance effects. Wide traces for VIN, VOUT, and GND will help reduce voltage drops and parasitic effects during dynamic operation as well as improve the thermal performance at high load current.

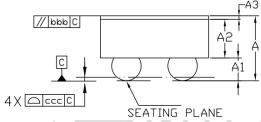


# Nano-Current Consumed, IoSmart™ LoadSwitch with Slew Rate Control

### **PACKAGE OUTLINE**







Dimensional Ref.							
REF.	Min.	Nom.	Max.				
Α	0.410	0.460	0.510				
Α1	0.135	0.160	0.185				
Α2	0.250	0.275	0.300				
Α3	0.020	0.025	0.030				
D	0.755	0.770	0.785				
Ε	0.755	0.770	0.785				
D1	0.350	0.400	0.450				
E1	0.350	0.400	0.450				
Ь	0.170	0.210	0.250				
е	0	).400 BSC					
SD	0	.200 BS	C				
SE	0	.200 BS	C				
To	ol. of Fo	rm&Pos	sition				
ааа	0.10						
ЬЬЬ	0.10						
CCC		0.05					
ddd		0.05					

# GRATED POWER

#### Notes

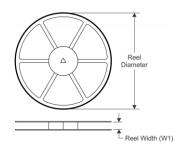
- 1. ALL DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGRESS)
- 2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M-1994.
- 3. A3: BACKSIDE LAMINATION

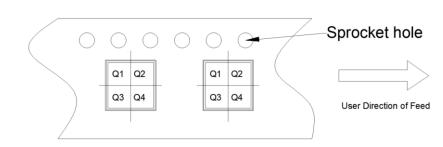
# Nano-Current Consumed, IoSmart<sup>™</sup> LoadSwitch with Slew Rate Control

### TAPE AND REEL INFORMATION

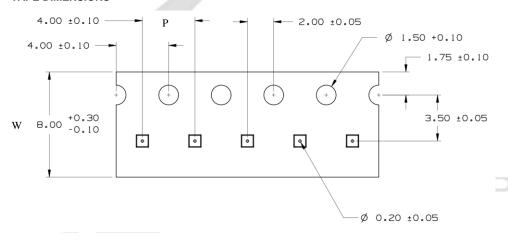
#### **REEL DIMENSIONS**

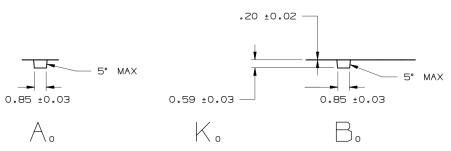
#### **QUADRANT ASSIGNMENTS PIN 1 ORIENTATION TAPE**





#### **TAPE DIMENSIONS**





Device	Package	Pins	SPQ	Reel Diameter(mm)	Reel Width W1	Α0	В0	K0	Р	w	Pin1
GLF71305	WLCSP	4	4000	180	9	0.85	0.85	0.59	4	8	Q1

#### Remark:

- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- C0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P: Pitch between successive cavity centers





# Nano-Current Consumed, IoSmart™ LoadSwitch with Slew Rate Control

## **SPECIFICATION DEFINITIONS**

Document Type	Meaning	Product Status
Target Specification	This is a target specification intended to support exploration and discussion of critical needs for a proposed or target device. Spec limits including typical, minimum, and maximum values are desired, or target, limits. GLF reserves the right to change limits at any time without warning or notification. A target specification in no way guarantees future production of the device in question.	Design / Development
Preliminary Specification	This is a draft version of a product specification. The specification is still under internal review and subject to change. GLF reserves the right to change the specification at any time without warning or notification. A preliminary specification in no way guarantees future production of the device in question.	Qualification
Product Specification	This document represents the anticipated production performance characteristics of the device.	Production

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